

## LM320L, LM79LXXAC Series 3-Terminal Negative Regulators

### General Description

The LM320L/LM79LXXAC series of 3-terminal negative voltage regulators features fixed output voltages of  $-5V$ ,  $-12V$ , and  $-15V$  with output current capabilities in excess of 100 mA. These devices were designed using the latest computer techniques for optimizing the packaged IC thermal/electrical performance. The LM79LXXAC series, even when combined with a minimum output compensation capacitor of  $0.1 \mu F$ , exhibits an excellent transient response, a maximum line regulation of  $0.07\% V_O/V$ , and a maximum load regulation of  $0.01\% V_O/mA$ .

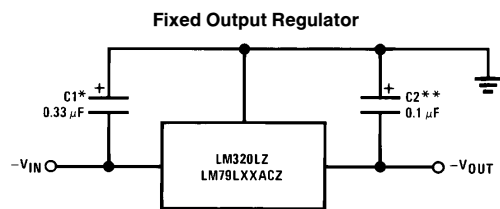
The LM320L/LM79LXXAC series also includes, as self-protection circuitry: safe operating area circuitry for output transistor power dissipation limiting, a temperature independent short circuit current limit for peak output current limiting, and a thermal shutdown circuit to prevent excessive junction temperature. Although designed primarily as fixed voltage regulators, these devices may be combined with simple external circuitry for boosted and/or adjustable voltages and currents. The LM79LXXAC series is available in the 3-lead TO-92 package, and SO-8; 8 lead package. The LM320L series is available in the 3-lead TO-92 package.

For output voltage other than  $-5V$ ,  $-12V$  and  $-15V$  the LM137L series provides an output voltage range from 1.2V to 47V.

### Features

- Preset output voltage error is less than  $\pm 5\%$  overload, line and temperature
- Specified at an output current of 100 mA
- Easily compensated with a small  $0.1 \mu F$  output capacitor
- Internal short-circuit, thermal and safe operating area protection
- Easily adjustable to higher output voltages
- Maximum line regulation less than  $0.07\% V_{OUT}/V$
- Maximum load regulation less than  $0.01\% V_{OUT}/mA$

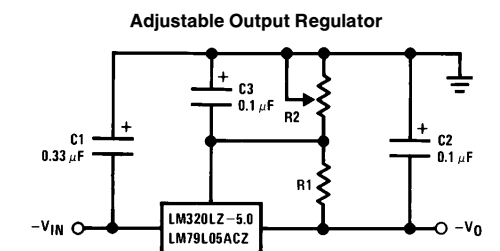
### Typical Applications



TL/H/7748-1

\*Required if the regulator is located far from the power supply filter. A  $1 \mu F$  aluminum electrolytic may be substituted.

\*\*Required for stability. A  $1 \mu F$  aluminum electrolytic may be substituted.

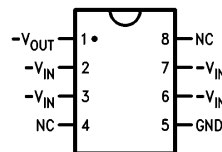


TL/H/7748-3

$$-V_O = -5V - (5V/R_1 + I_O) \cdot R_2, \\ 5V/R_1 > 3 I_O$$

### Connection Diagrams

#### SO-8 Plastic (Narrow Body)

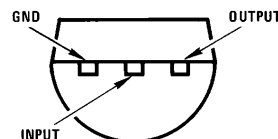


TL/H/7748-4

#### Top View

Order Number LM79L05ACM,  
LM79L12ACM or LM79L15ACM  
See NS Package Number M08A

#### TO-92 Plastic Package (Z)



TL/H/7748-2

#### Bottom View

Order Number LM320LZ-5.0, LM79L05ACZ,  
LM320LZ-12, LM79L12ACZ, LM320LZ-15 or  
LM79L15ACZ  
See NS Package Number Z03A

## Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Input Voltage

$$V_O = -5V, -12V, -15V$$

-35V

Internal Power Dissipation (Note 1)

Internally Limited

Operating Temperature Range

0°C to +70°C

Maximum Junction Temperature

+125°C

Storage Temperature Range

-55°C to +150°C

Lead Temperature (Soldering, 10 sec.)

260°C

## Electrical Characteristics (Note 2) $T_A = 0^\circ\text{C}$ to $+70^\circ\text{C}$ unless otherwise noted.

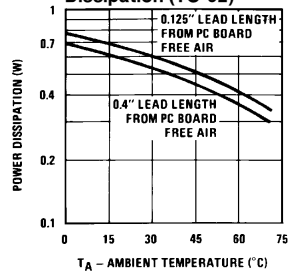
Output Voltage			− 5V			− 12V			− 15V			Units
Input Voltage (unless otherwise noted)			− 10V			− 17V			− 20V			
Symbol	Parameter	Conditions	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
V <sub>O</sub>	Output Voltage	T <sub>J</sub> = 25°C, I <sub>O</sub> = 100 mA	−5.2	−5	−4.8	−12.5	−12	−11.5	−15.6	−15	−14.4	V
		1 mA ≤ I <sub>O</sub> ≤ 100 mA	−5.25		−4.75	−12.6		−11.4	−15.75		−14.25	
		V <sub>MIN</sub> ≤ V <sub>IN</sub> ≤ V <sub>MAX</sub>	(−20 ≤ V <sub>IN</sub> ≤ −7.5)			(−27 ≤ V <sub>IN</sub> ≤ −14.8)			(−30 ≤ V <sub>IN</sub> ≤ −18)			
		1 mA ≤ I <sub>O</sub> ≤ 40 mA	−5.25		−4.75		−12.6	−11.4	−15.75		−14.25	
		V <sub>MIN</sub> ≤ V <sub>IN</sub> ≤ V <sub>MAX</sub>	(−20 ≤ V <sub>IN</sub> ≤ −7)			(−27 ≤ V <sub>IN</sub> ≤ −14.5)			(−30 ≤ V <sub>IN</sub> ≤ −17.5)			
ΔV <sub>O</sub>	Line Regulation	T <sub>J</sub> = 25°C, I <sub>O</sub> = 100 mA	60			45			45			mV
		V <sub>MIN</sub> ≤ V <sub>IN</sub> ≤ V <sub>MAX</sub>	(−20 ≤ V <sub>IN</sub> ≤ −7.3)			(−27 ≤ V <sub>IN</sub> ≤ −14.6)			(−30 ≤ V <sub>IN</sub> ≤ −17.7)			V
		T <sub>J</sub> = 25°C, I <sub>O</sub> = 40 mA	60			45			45			mV
		V <sub>MIN</sub> ≤ V <sub>IN</sub> ≤ V <sub>MAX</sub>	(−20 ≤ V <sub>IN</sub> ≤ −7)			(−27 ≤ V <sub>IN</sub> ≤ −14.5)			(−30 ≤ V <sub>IN</sub> ≤ −17.5)			V
ΔV <sub>O</sub>	Load Regulation	T <sub>J</sub> = 25°C 1 mA ≤ I <sub>O</sub> ≤ 100 mA	50			100			125			mV
ΔV <sub>O</sub>	Long Term Stability	I <sub>O</sub> = 100 mA	20			48			60			mV/khrs
I <sub>Q</sub>	Quiescent Current	I <sub>O</sub> = 100 mA	2    6			2    6			2    6			mA
ΔI <sub>Q</sub>	Quiescent Current Change	1 mA ≤ I <sub>O</sub> ≤ 100 mA	0.3			0.3			0.3			mA
		1 mA ≤ I <sub>O</sub> ≤ 40 mA	0.1			0.1			0.1			
		I <sub>O</sub> = 100 mA	0.25			0.25			0.25			mA
		V <sub>MIN</sub> ≤ V <sub>IN</sub> ≤ V <sub>MAX</sub>	(−20 ≤ V <sub>IN</sub> ≤ −7.5)			(−27 ≤ V <sub>IN</sub> ≤ −14.8)			(−30 ≤ V <sub>IN</sub> ≤ −18)			V
V <sub>n</sub>	Output Noise Voltage	T <sub>J</sub> = 25°C, I <sub>O</sub> = 100 mA f = 10 Hz − 10 kHz	40			96			120			μV
$\frac{\Delta V_{IN}}{\Delta V_O}$	Ripple Rejection	T <sub>J</sub> = 25°C, I <sub>O</sub> = 100 mA f = 120 Hz	50			52			50			dB
	Input Voltage Required to Maintain Line Regulation	T <sub>J</sub> = 25°C, I <sub>O</sub> = 100 mA	−7.3			−14.6			−17.7			V
		I <sub>O</sub> = 40 mA	−7.0			−14.5			−17.5			V

**Note 1:** Thermal resistance of Z package is  $60^\circ\text{C/W}$   $\theta_{JC}$ ,  $232^\circ\text{C/W}$   $\theta_{JA}$  at still air, and  $88^\circ\text{C/W}$  at 400 ft/min of air. The M package  $\theta_{JA}$  is  $180^\circ\text{C/W}$  in still air. The maximum junction temperature shall not exceed  $125^\circ\text{C}$  on electrical parameters.

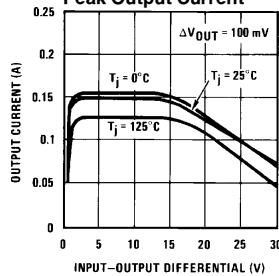
**Note 2:** To ensure constant junction temperature, low duty cycle pulse testing is used.

## Typical Performance Characteristics

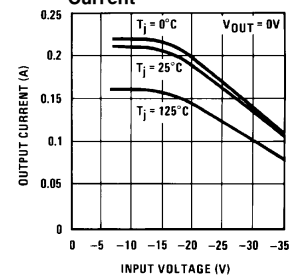
**Maximum Average Power Dissipation (TO-92)**



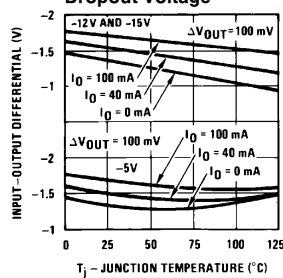
**Peak Output Current**



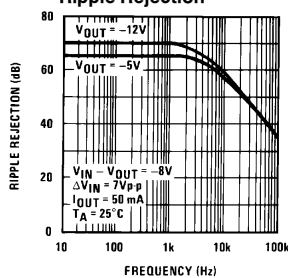
**Short Circuit Output Current**



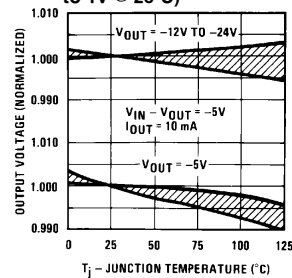
**Dropout Voltage**



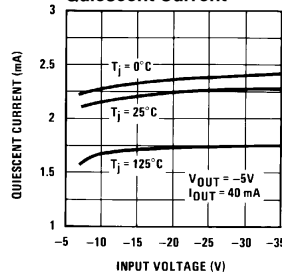
**Ripple Rejection**



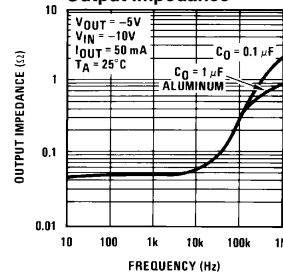
**Output Voltage vs. Temperature (Normalized to 1V @  $25^{\circ}\text{C}$ )**



**Quiescent Current**



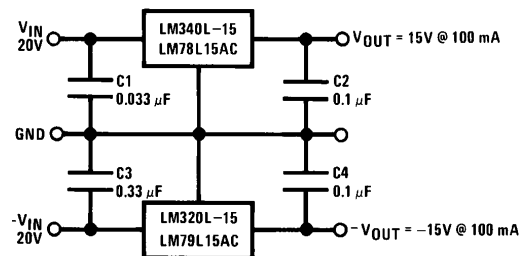
**Output Impedance**



TL/H/7748-5

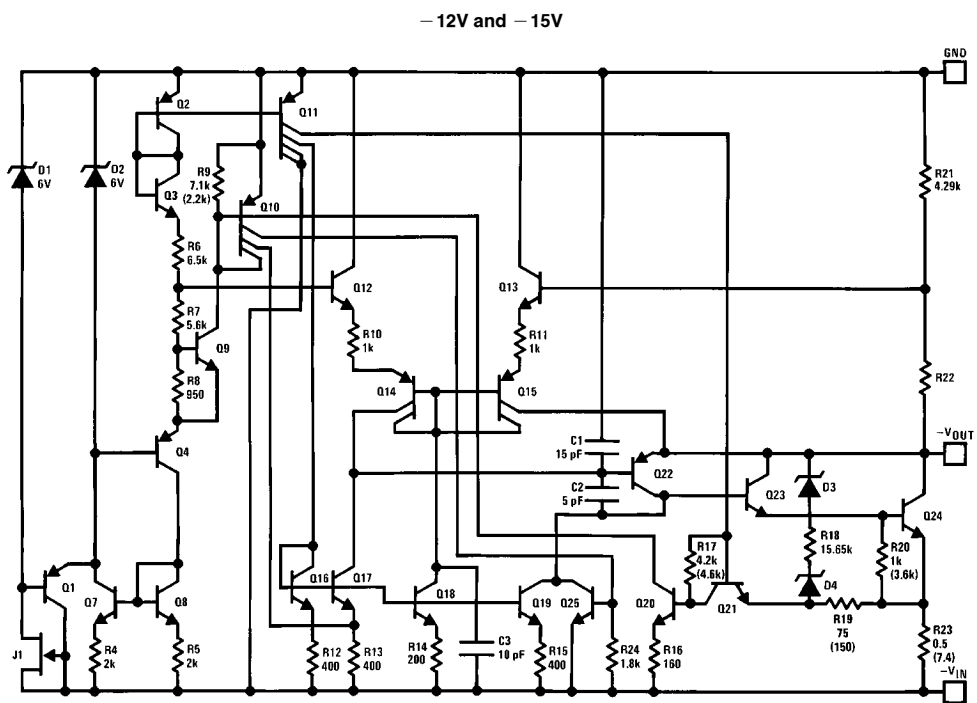
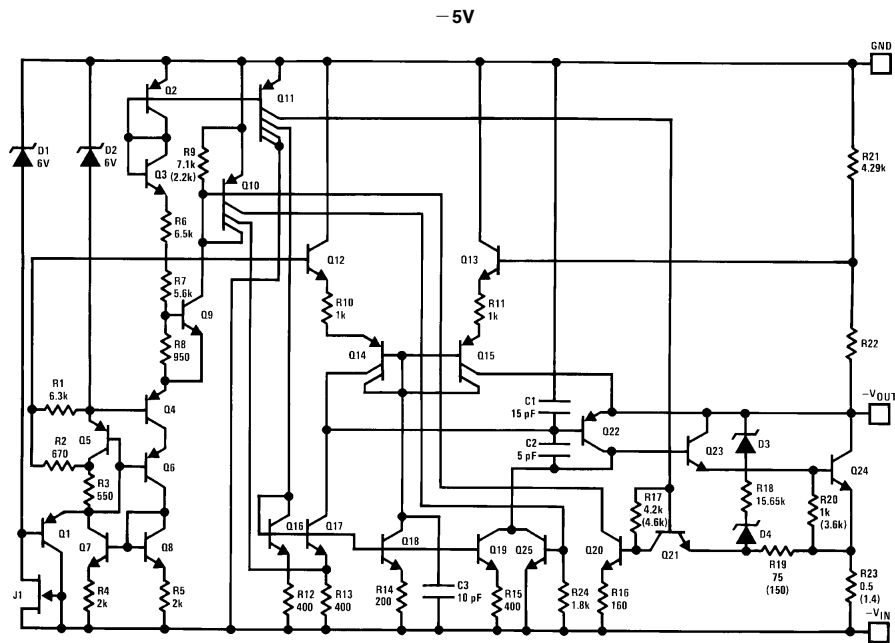
## Typical Applications (Continued)

**$\pm 15\text{V}$ , 100 mA Dual Power Supply**

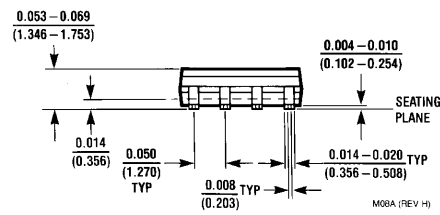
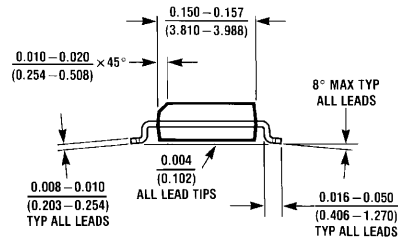
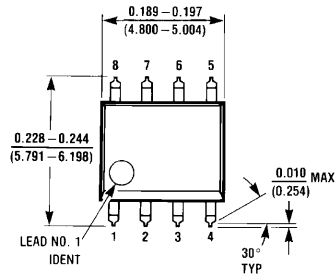


TL/H/7748-6

## Schematic Diagrams

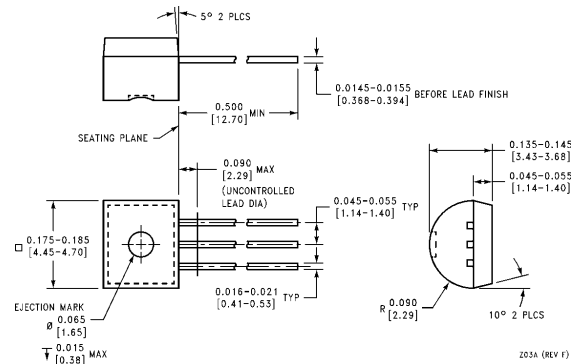


# Physical Dimensions inches (millimeters)



**S.O. Package (M)**  
**Order Number LM79L05ACM, LM79L12ACM or LM79L15ACM**  
**NS Package Number M08A**

## Physical Dimensions inches (millimeters) (Continued)



**Molded Offset TO-92 (Z)**  
**Order Number LM320LZ-5.0, LM79L05ACZ, LM320LZ-12,**  
**LM79L12ACZ, LM320LZ-15 or LM79L15ACZ**  
**NS Package Number Z03A**

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